



High Quality Audio Dual Operational Amplifier

■ GENERAL DESCRIPTION

The MUSES8820 is a high quality audio operational amplifier, which is optimized for high-end audio and professional audio applications.

It is the best for audio preamplifiers, active filters, and line amplifiers with excellent sound.

■ FEATURES

- Operating Voltage $V_{opr} = \pm 3.5V$ to $\pm 16V$
- Output noise $4.5nV/\sqrt{Hz}$ at $f=1kHz$
- Input Offset Voltage $0.3mV$ typ. $3mV$ max.
- Input Bias Current $100nA$ typ. $500nA$ max. at $T_a=25^\circ C$
- Voltage Gain $110dB$ typ.
- Slew Rate $5V/\mu s$ typ.
- Bipolar Technology
- Package Outline DIP8, SOP8 JEDEC 150mil

■ PACKAGE OUTLINE



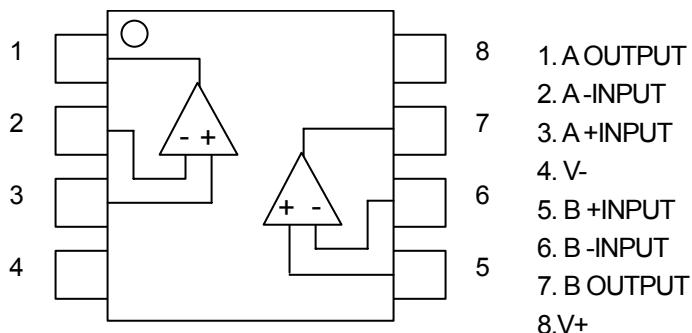
MUSES8820D
(DIP8)



MUSES8820E
(SOP8)

■ PIN CONFIGURATION

PIN FUNCTION



MUSES8820

■ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V ⁺ /V ⁻	±18	V
Common Mode Input Voltage	V _{ICM}	±15 (Note1)	V
Differential Input Voltage	V _{ID}	±30	V
Power Dissipation	P _D	DIP8 : 870 SOP8 : 900(Note2)	mW
Output Current	I _O	±50	mA
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-50 to +150	°C

(Note1) For supply Voltages less than ±15 V, the maximum input voltage is equal to the Supply Voltage.

(Note2) Mounted on the EIA/JEDEC standard board (114.3×76.2×1.6mm, two layer, FR-4).

■RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V ⁺ /V ⁻	-	±3.5	-	±16	V

■ELECTRIC CHARACTERISTICS

DC CHARACTERISTICS (V⁺/V⁻=±15V, Ta=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I _{cc}	No Signal, R _L =∞	-	8.0	12.0	mA
Input Offset Voltage	V _{IO}	R _S ≤10kΩ (Note3)	-	0.3	3.0	mV
Input Bias Current	I _B	(Note3, 4)	-	100	500	nA
Input Offset Current	I _{IO}	(Note3, 4)	-	5	200	nA
Voltage Gain	A _V	R _L ≥2kΩ, V _o =±10V R _S ≤10kΩ	90	110	-	dB
Common Mode Rejection Ratio	CMR	V _{ICM} =±12V (Note5) R _S ≤10kΩ	80	110	-	dB
Supply Voltage Rejection Ratio	SVR	V ⁺ /V ⁻ =±3.5 to ±16.0V R _S ≤10kΩ (Note3, 6)	80	110	-	dB
Max Output Voltage	V _{OM}	R _L =2kΩ	±12	±13.5	-	V
Input Common Mode Voltage Range	V _{ICM}	CMR≥80dB	±12	±13.5	-	V

(Note3) Measured at V_{ICM}=0V

(Note4) Written by the absolute rate.

(Note5) CMR is calculated by specified change in offset voltage. (V_{ICM}=0V to +12V and V_{ICM}=0V to -12V)

(Note6) SVR is calculated by specified change in offset voltage. (V⁺/V⁻=±3.5V to ±16V)

AC CHARACTERISTICS ($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GB	$f=10\text{kHz}$	-	11	-	MHz
Unity Gain Frequency	f_T	$A_V=+100, R_S=100\Omega, R_L=2k\Omega, C_L=10\text{pF}$	-	5.8	-	MHz
Phase Margin	ϕ_M	$A_V=+100, R_S=100\Omega, R_L=2k\Omega, C_L=10\text{pF}$	-	48	-	deg
Input Noise Voltage1	V_{NI}	$f=1\text{kHz}, A_V=+100, R_S=100\Omega, R_L=\infty$	-	4.5	-	nV/ $\sqrt{\text{Hz}}$
Input Noise Voltage2	V_{N2}	$f=1\text{kHz}, A_V=+10, R_S=2.2k\Omega, \text{RIAA, } 30\text{kHz LPF}$	-	0.8	1.4	μVrms
Total Harmonic Distortion	THD	$f=1\text{kHz}, A_V=+10, R_L=2k\Omega, V_o=5\text{Vrms}$	-	0.001	-	%
Channel Separation	CS	$f=1\text{kHz}, A_V=-+100, R_S=1k\Omega, R_L=2k\Omega$	-	140	-	dB
Positive Slew Rate	+SR	$A_V=1, V_{IN}=2V_{pp}, R_L=2k\Omega, C_L=10\text{pF}$	-	5	-	V/ μs
Negative Slew Rate	-SR	$A_V=1, V_{IN}=2V_{pp}, R_L=2k\Omega, C_L=10\text{pF}$	-	5	-	V/ μs

■Application Notes

•Package Power, Power Dissipation and Output Power

IC is heated by own operation and possibly gets damage when the junction power exceeds the acceptable value called Power Dissipation P_D . The dependence of the MUSES8820 P_D on ambient temperature is shown in Fig 1. The plots are depended on following two points. The first is P_D on ambient temperature 25°C, which is the maximum power dissipation. The second is 0W, which means that the IC cannot radiate any more. Conforming the maximum junction temperature T_{jmax} to the storage temperature T_{stg} derives this point. Fig.1 is drawn by connecting those points and conforming the P_D lower than 25°C to it on 25°C. The P_D is shown following formula as a function of the ambient temperature between those points.

$$\text{Dissipation Power } P_D = \frac{T_{jmax} - T_a}{\theta_{ja}} [\text{W}] \quad (\text{Ta}=25^\circ\text{C} \text{ to } \text{Ta}=150^\circ\text{C})$$

Where, θ_{ja} is heat thermal resistance which depends on parameters such as package material, frame material and so on. Therefore, P_D is different in each package.

While, the actual measurement of dissipation power on MUSES8820 is obtained using following equation.

$$(\text{Actual Dissipation Power}) = (\text{Supply Current } I_{cc}) \times (\text{Supply Voltage } V^+ - V) - (\text{Output Power } P_o)$$

The MUSES8820 should be operated in lower than P_D of the actual dissipation power.

To sustain the steady state operation, take account of the Dissipation Power and thermal design.

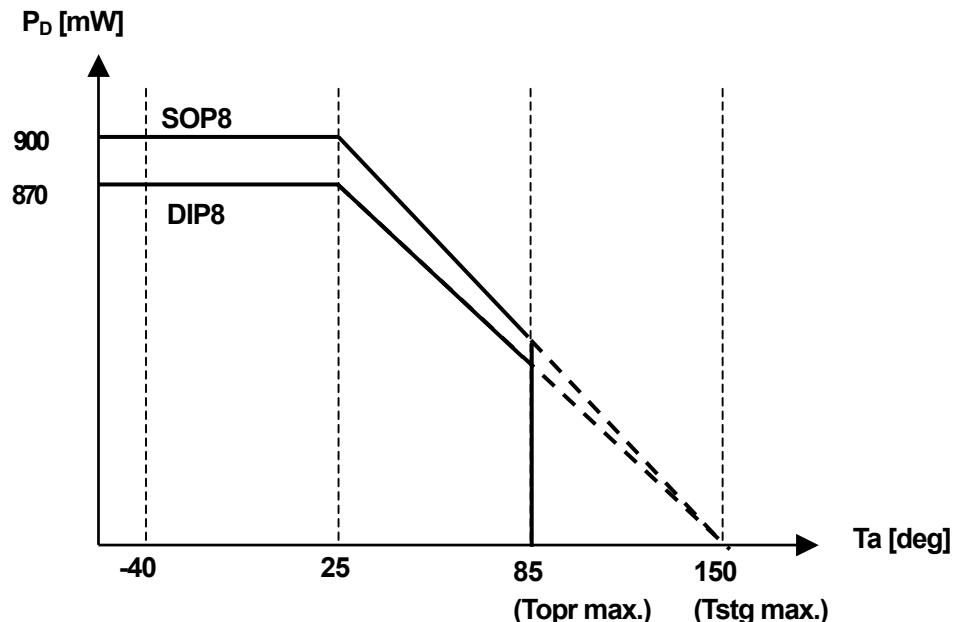
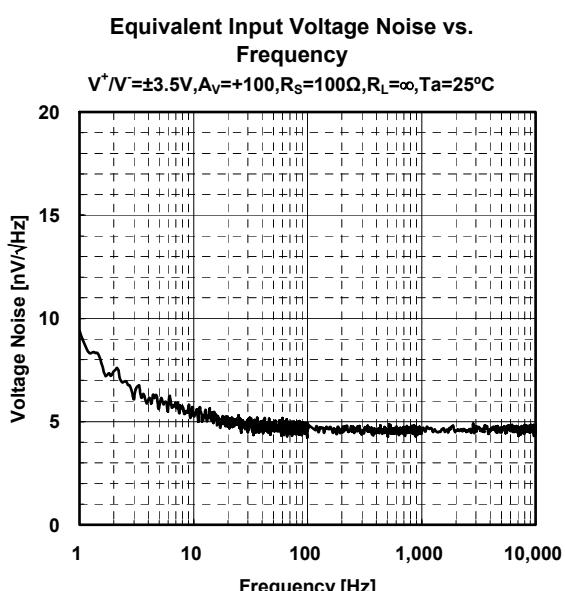
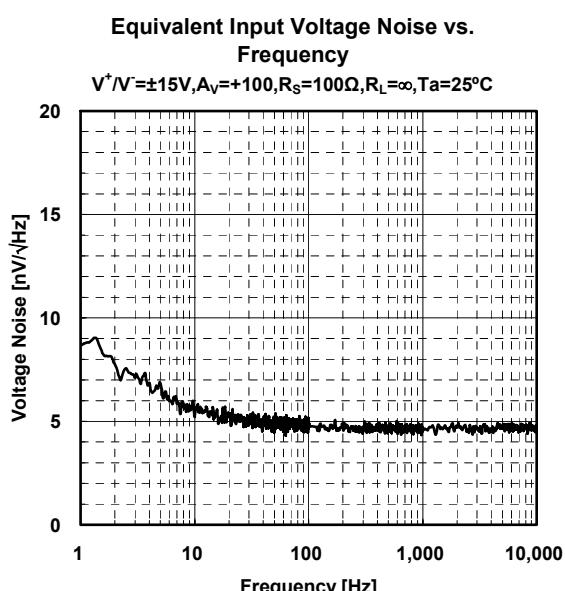
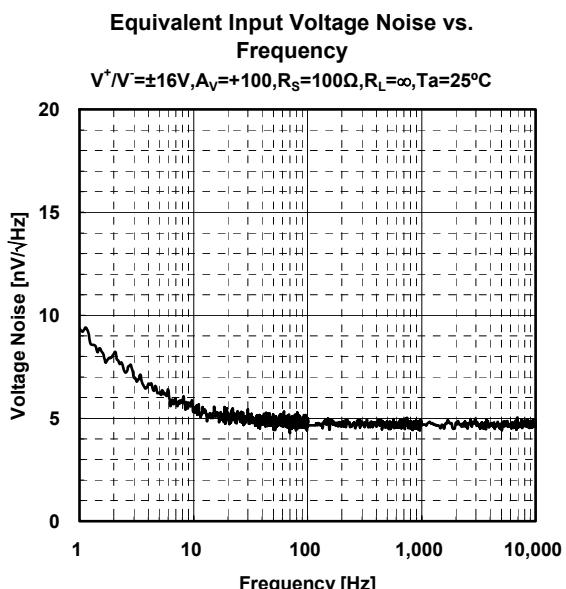
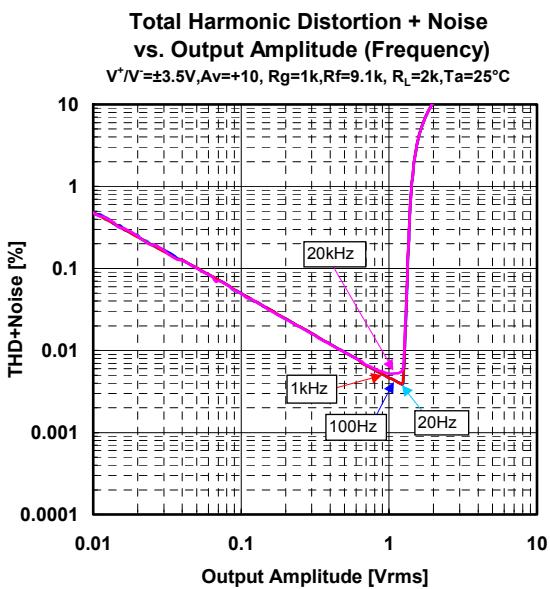
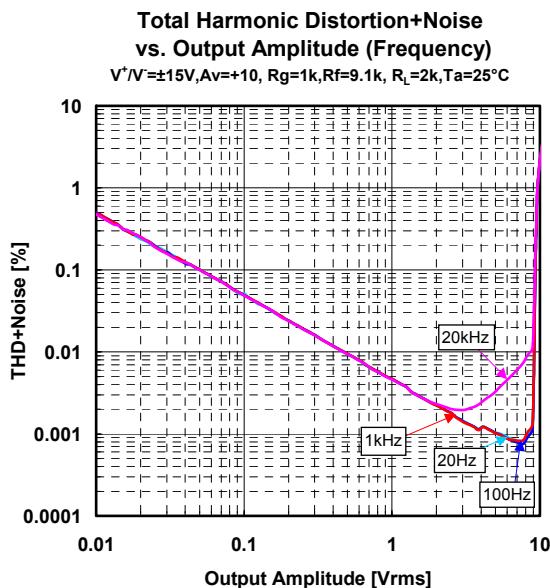
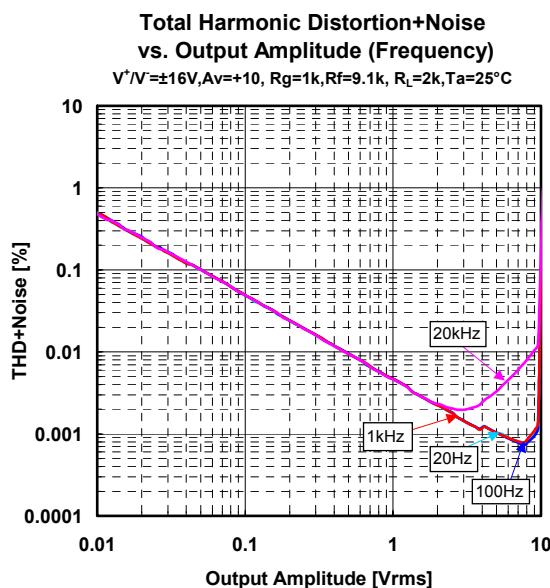
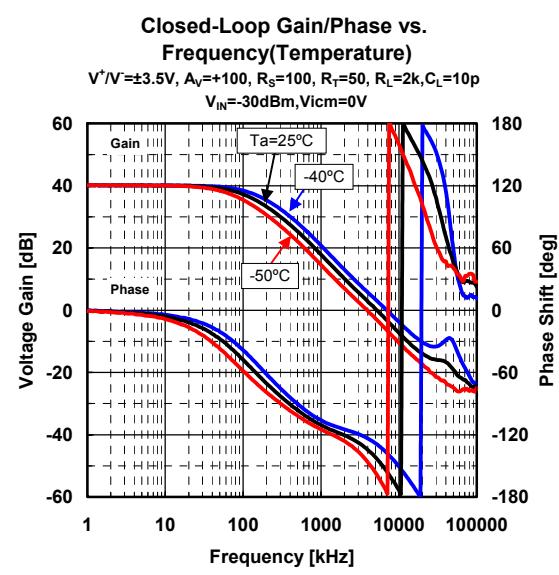
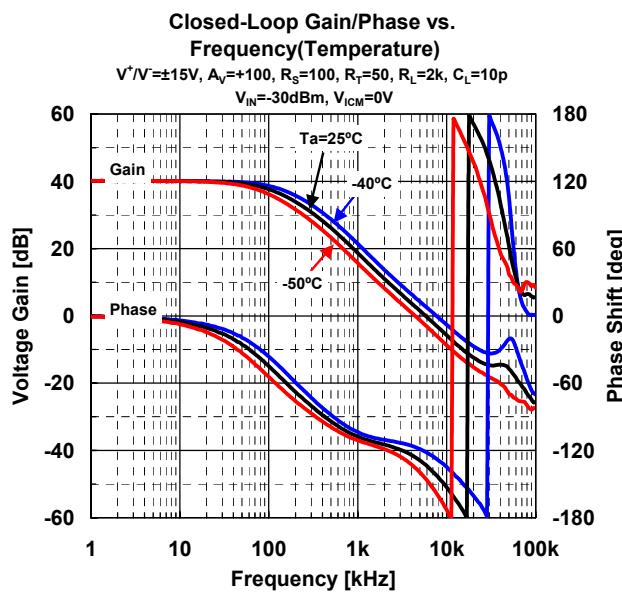
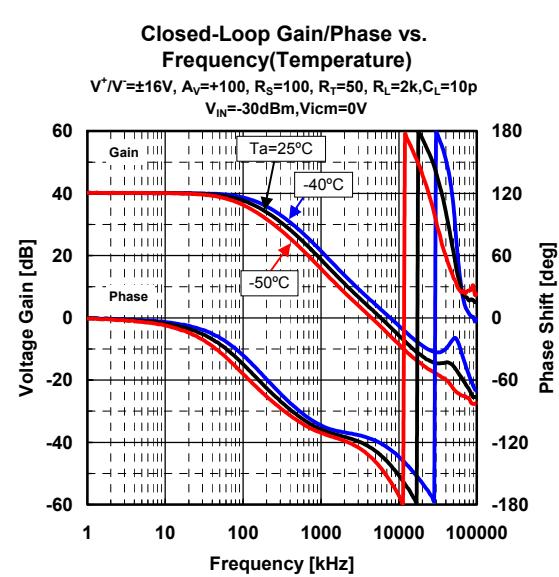
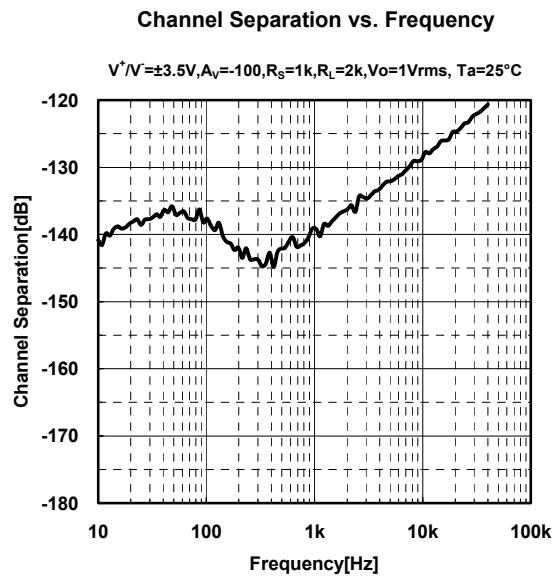
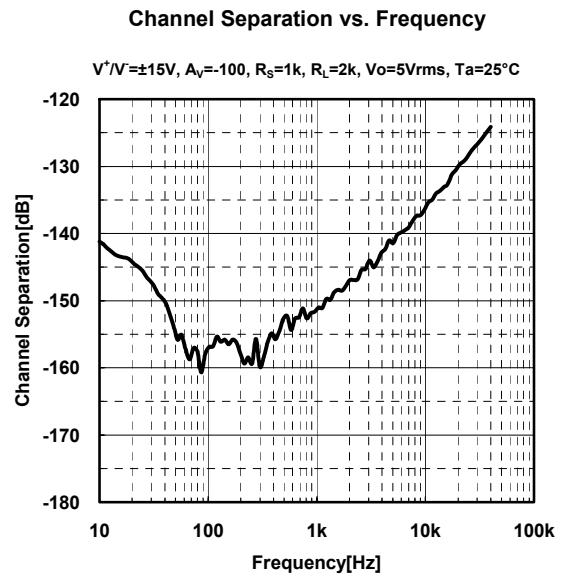
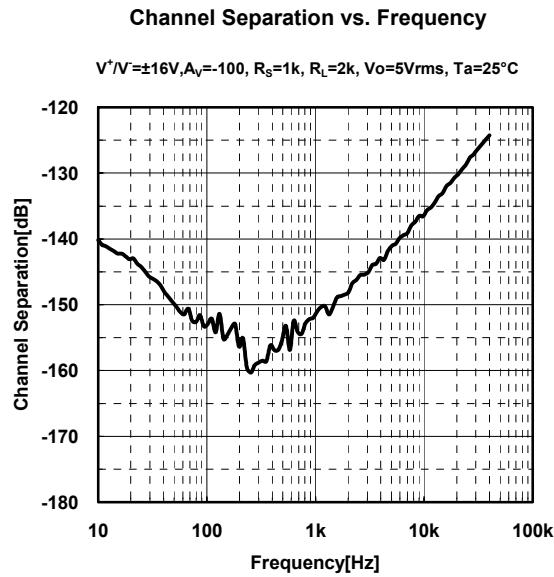


Fig.1 Power Dissipations vs. Ambient Temperature on the MUSES8820

TYPICAL CHARACTERISTICS



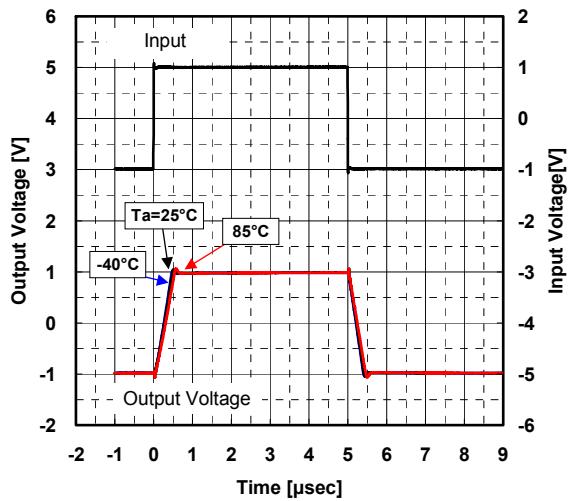
MUSES8820



Transient Response (Temperature)

$V^+/V^- = \pm 16V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

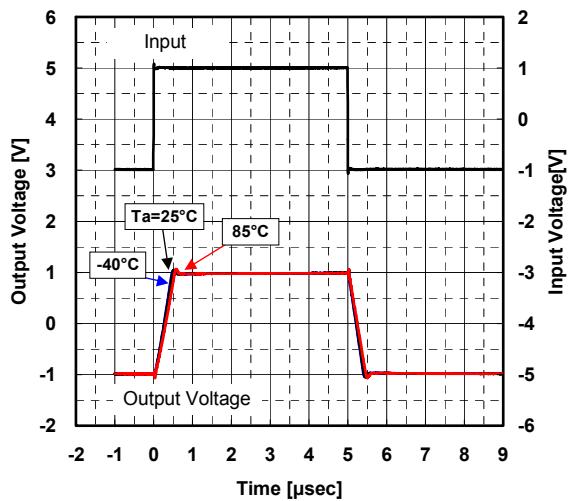
PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$



Transient Response (Temperature)

$V^+/V^- = \pm 15V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

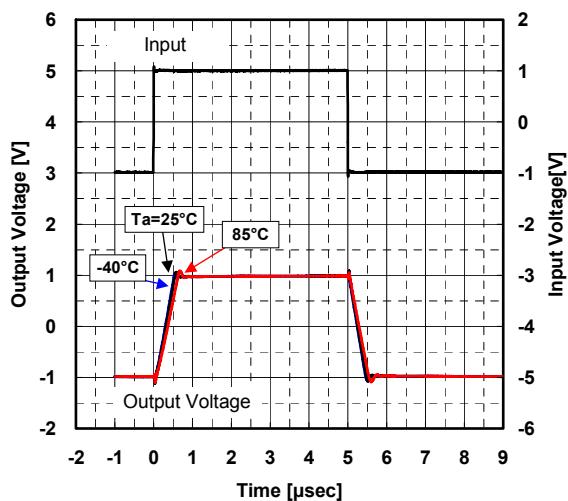
PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$



Transient Response (Temperature)

$V^+/V^- = \pm 3.5V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

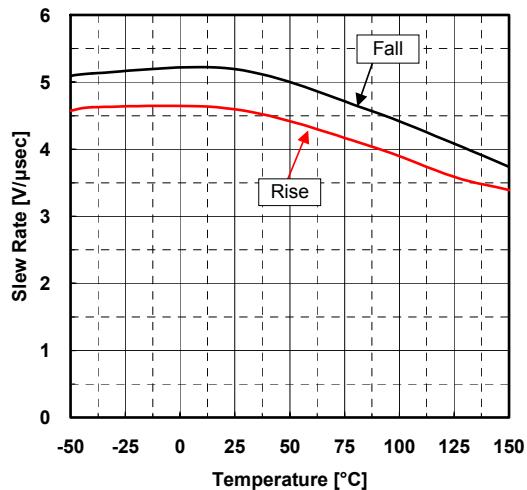
PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$



Slew Rate vs. Temperature

$V^+/V^- = \pm 16V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

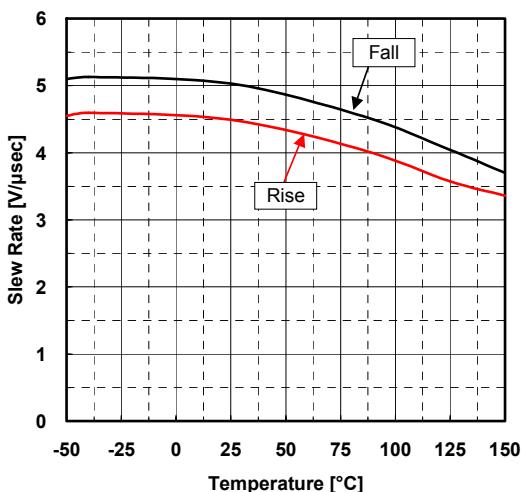
PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$



Slew Rate vs. Temperature

$V^+/V^- = \pm 15V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

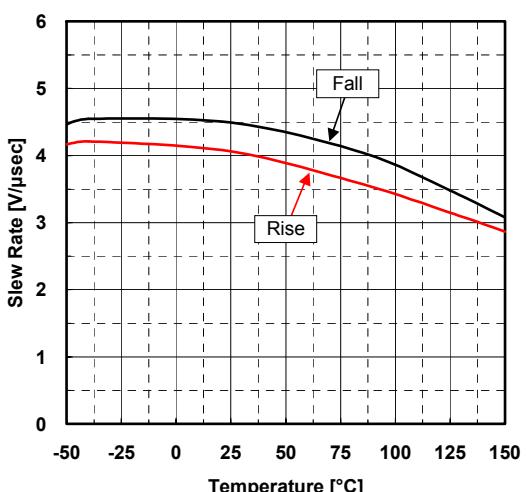
PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$



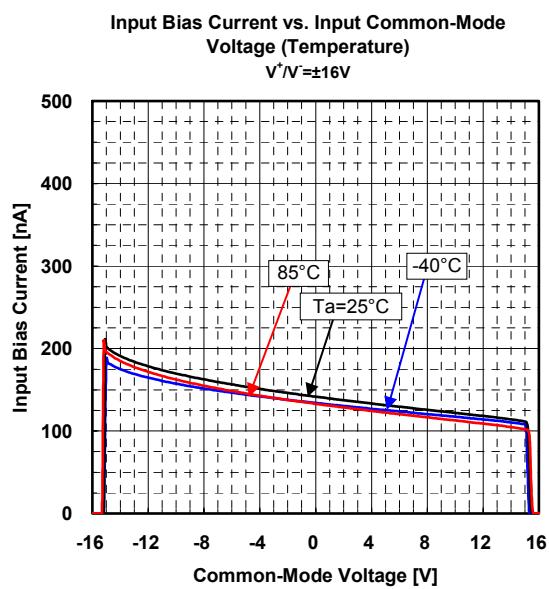
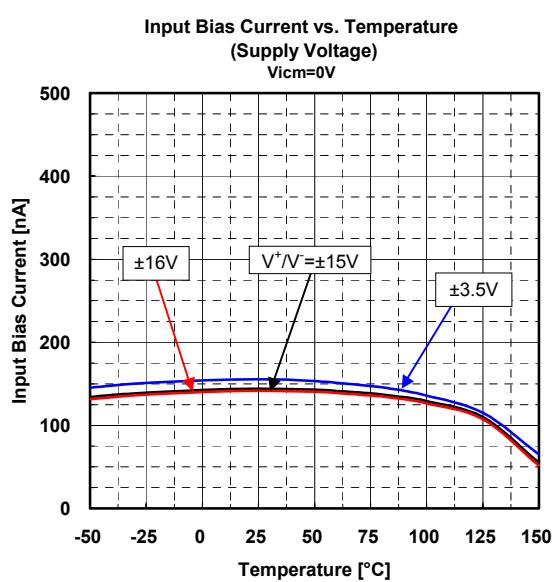
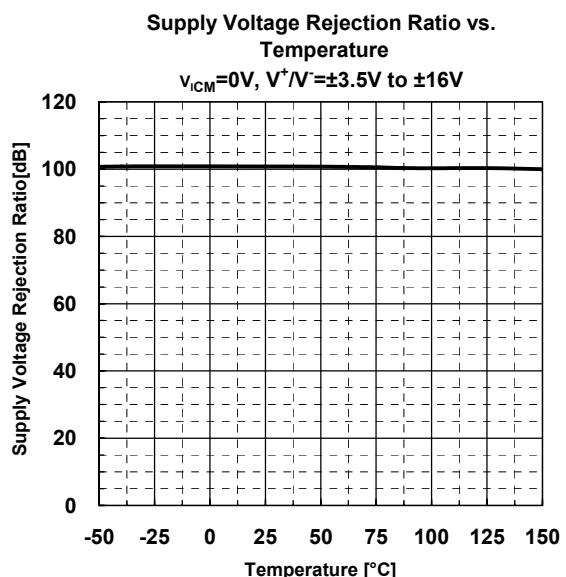
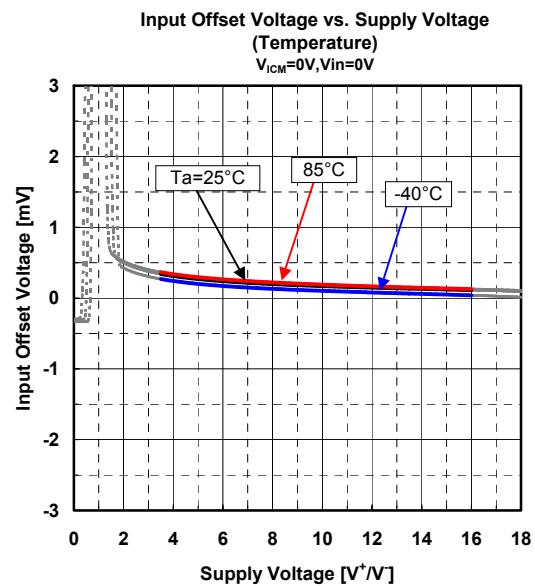
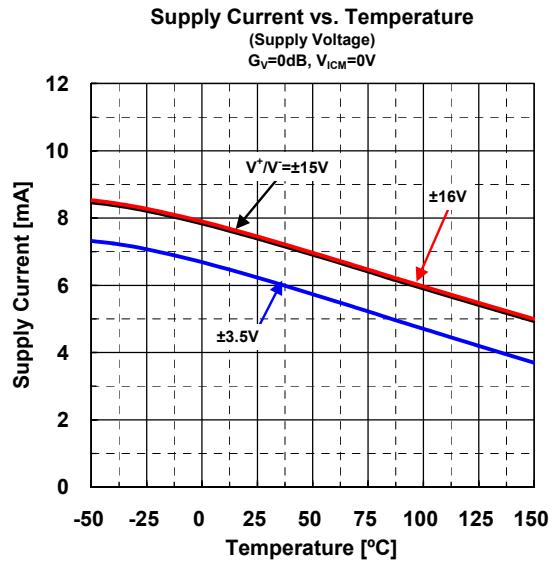
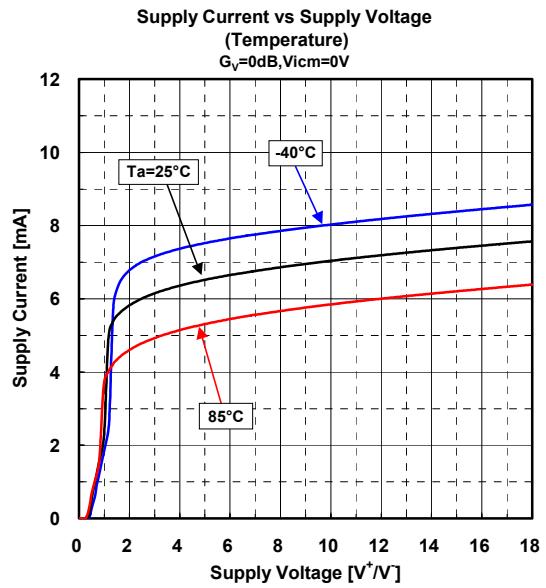
Slew Rate vs. Temperature

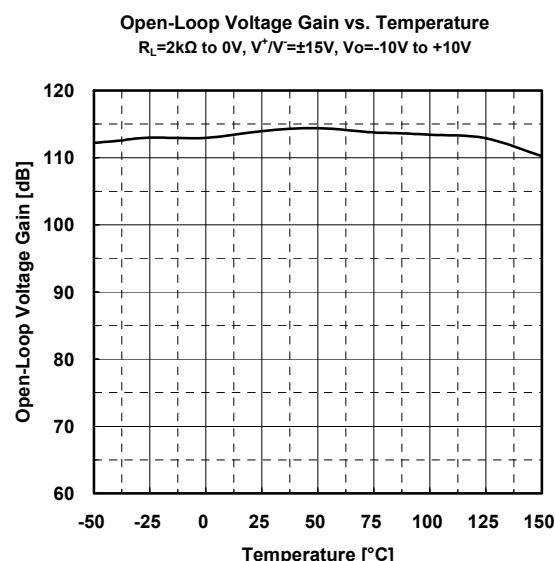
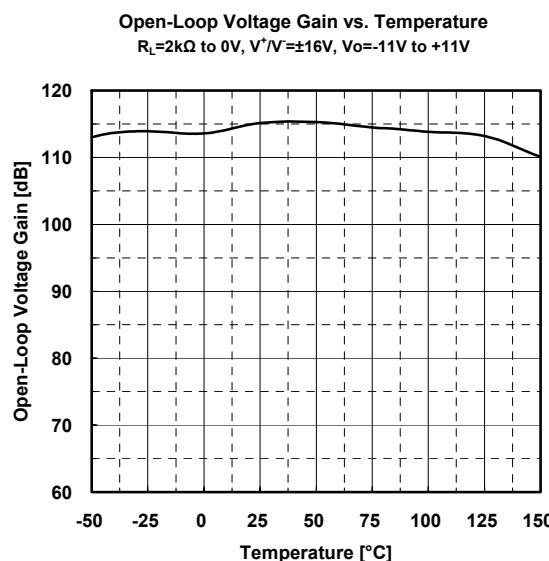
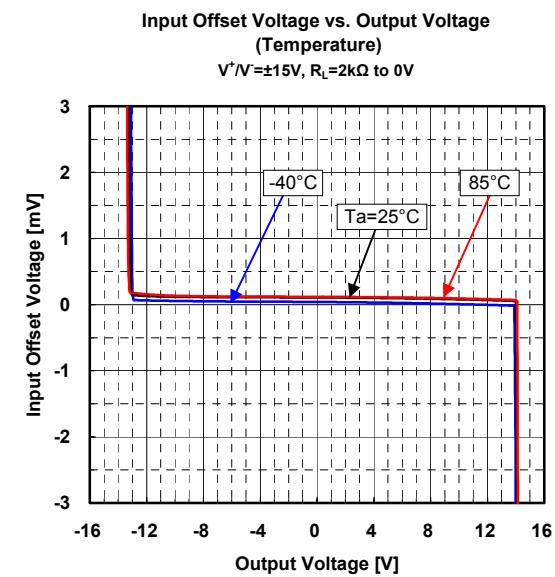
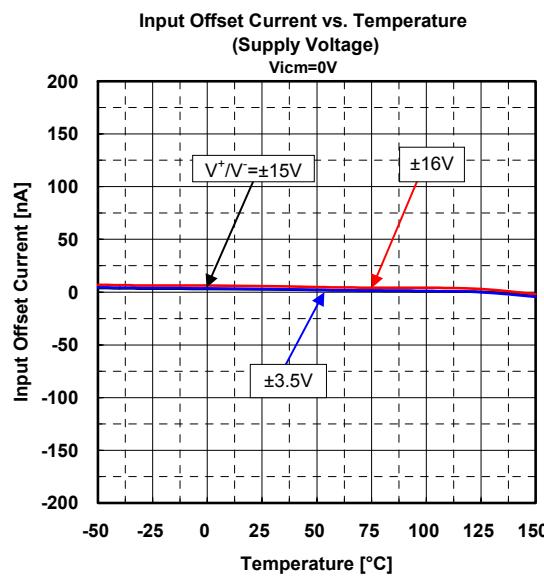
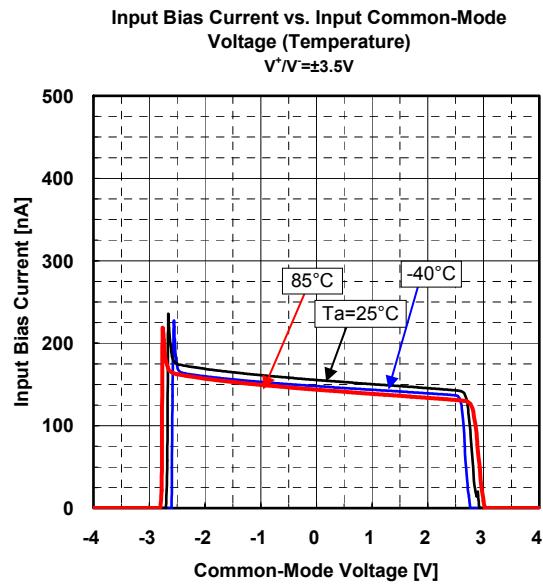
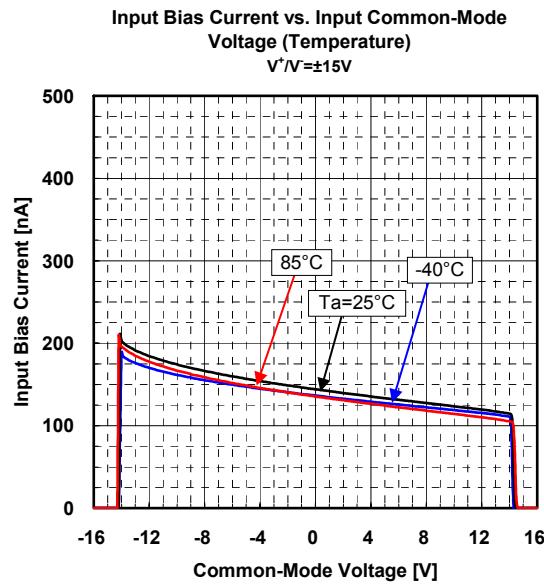
$V^+/V^- = \pm 3.5V$, $V_{IN} = 2V_{P,P}$, $f = 100kHz$

PulseEdge=10nsec, Gv=0dB, $C_L = 10p$, $R_L = 2k$

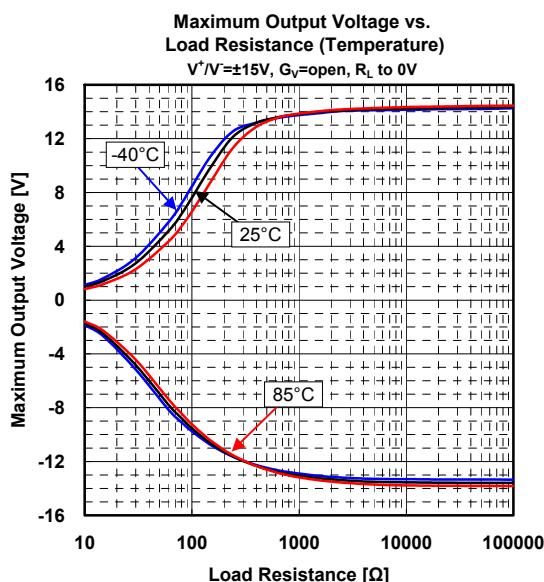
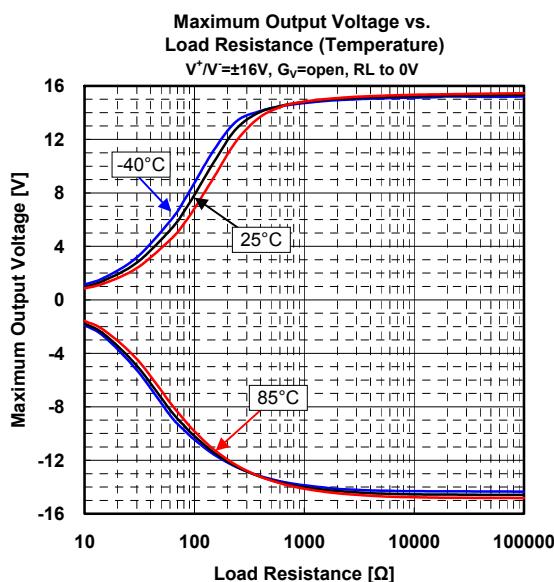
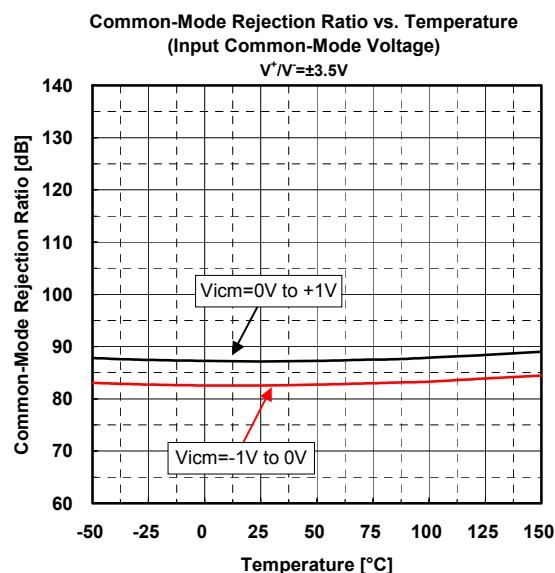
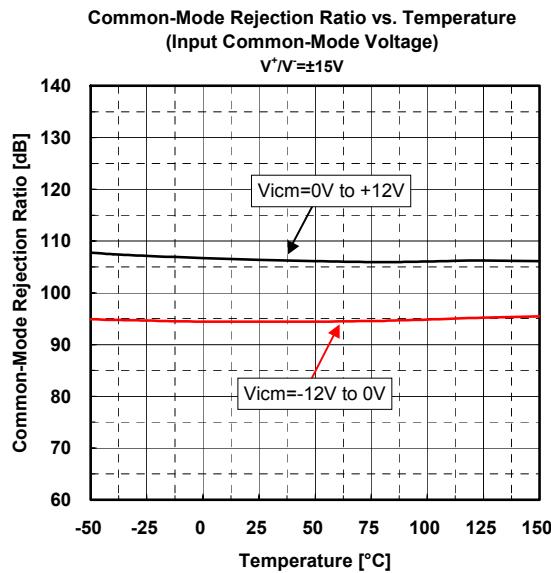
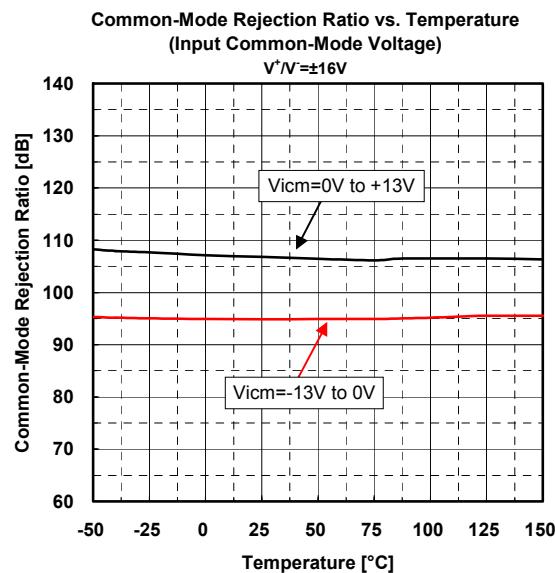
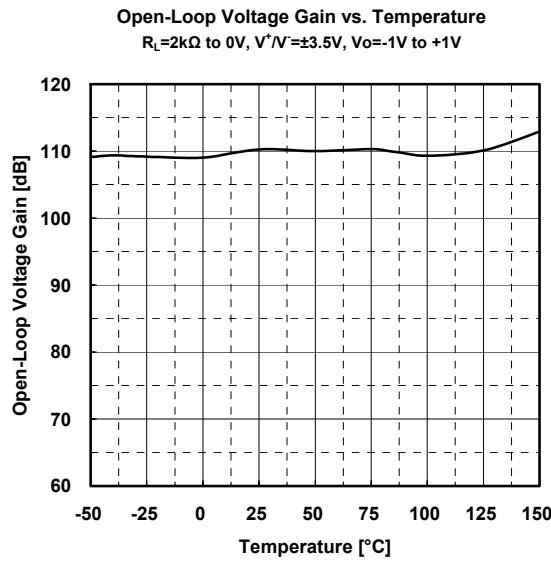


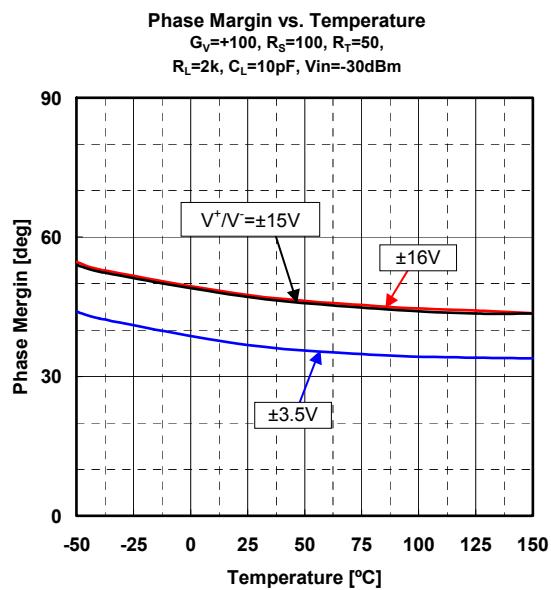
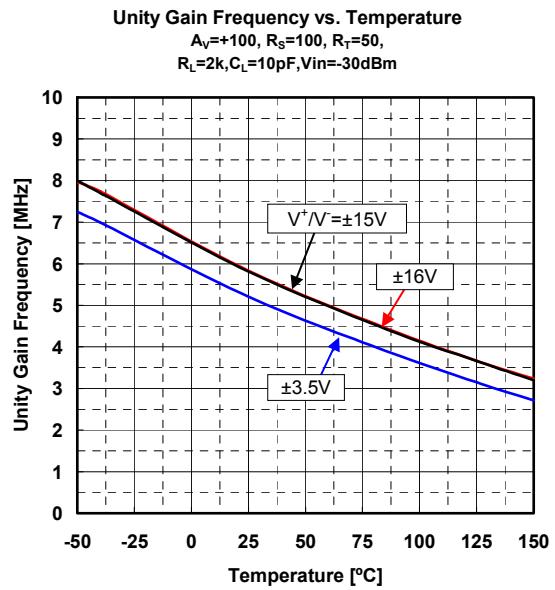
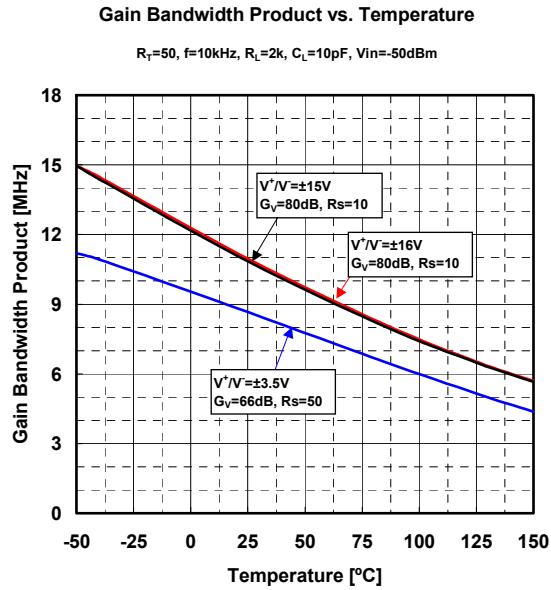
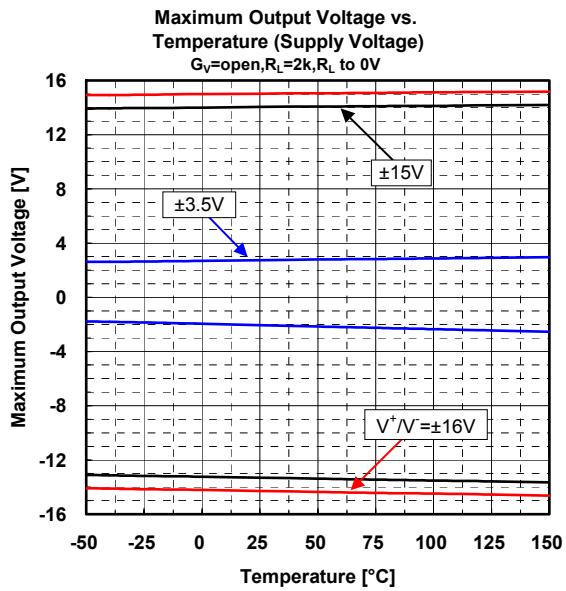
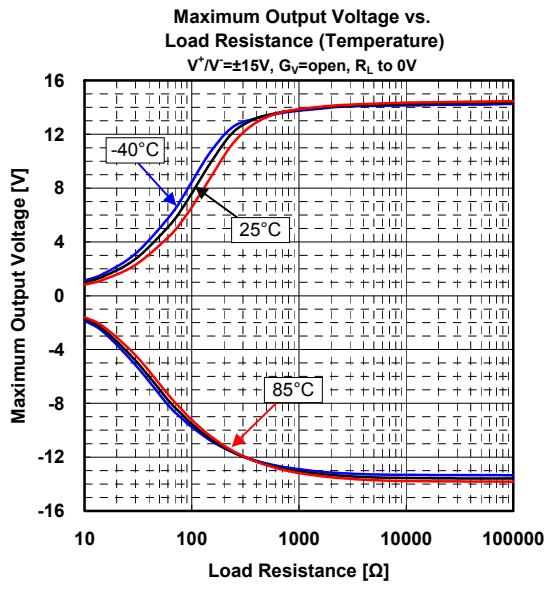
MUSES8820





MUSES8820





MUSES8820

MEMO

[CAUTION]
The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.